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6 A, 600 V, Ultrafast Diode

The RURD660, RURD660S is an ultrafast diode with low forward voltage drop. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial application.

Features

- Ultrafast Recovery t_{rr} = 60 ns (@ I_F = 6 A)
- Max Forward Voltage, V_F = 1.5 V (@ T_C = 25°C)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Ordering Information

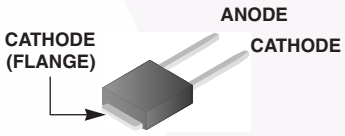
PART NUMBER	PACKAGE	BRAND
RURD660	TO-251-2L	RUR660
RURD660S	TO-252-3L	RUR660

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252 variant in the tape and reel, i.e., RURD660S9A.

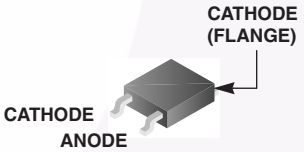
Symbol

Packaging

JEDEC STYLE TO-251



JEDEC STYLE TO-252



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

		RURD660 RURD660S	UNIT
Peak Repetitive Reverse Voltage	V_{RRM}	600	V
Working Peak Reverse Voltage	V_{RWM}	600	V
DC Blocking Voltage	V_R	600	V
Average Rectified Forward Current (T_C = 155°C)	$I_{F(AV)}$	6	A
Repetitive Peak Surge Current (Square Wave, 20 kHz)	I_{FRM}	12	A
Nonrepetitive Peak Surge Current (Halfwave, 1 Phase, 60 Hz)	I_{FSM}	60	A
Maximum Power Dissipation	P_D	50	W
Avalanche Energy (See Figures 10 and 11)	E_{AVL}	10	mJ
Operating and Storage Temperature	T_{STG}, T_J	-65 to 175	°C
Maximum Lead Temperature for Soldering			
Leads at 0.063 in. (1.6mm) from case for 10s	T_L	300	°C
Package Body for 10s, see Tech Brief 334	T_{PKG}	260	°C

Electrical Specifications $T_C = 25^oC$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
V_F	I_F = 6 A	-	-	1.5	V
	I_F = 6 A, $T_C = 150^oC$	-	-	1.2	V
I_R	V_R = 600 V	-	-	100	μA
	V_R = 600 V, $T_C = 150^oC$	-	-	500	μA
t_{rr}	I_F = 1 A, dI_F/dt = 200 A/μs	-	-	55	ns
	I_F = 6 A, dI_F/dt = 200 A/μs	-	-	60	ns
t_a	I_F = 6 A, dI_F/dt = 200 A/μs	-	28	-	ns
t_b	I_F = 6 A, dI_F/dt = 200 A/μs	-	16	-	ns
Q_{RR}	I_F = 6 A, dI_F/dt = 200 A/μs	-	150	-	nC
C_J	V_R = 10 V, I_F = 0 A	-	25	-	pF
$R_{\theta JC}$		-	-	3	$^oC/W$

DEFINITIONS

V_F = Instantaneous forward voltage (pw = 300 μs, D = 2%).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

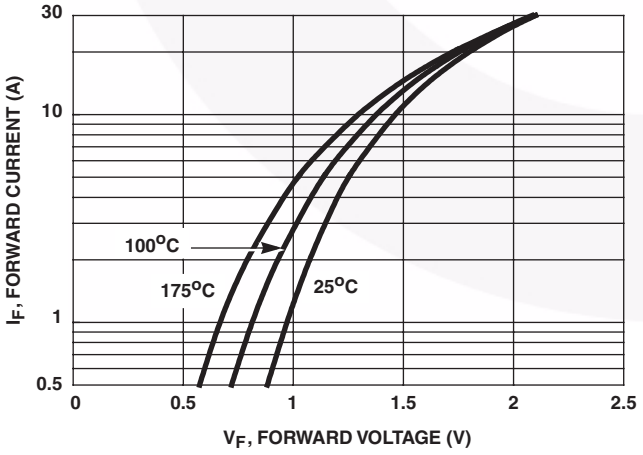


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

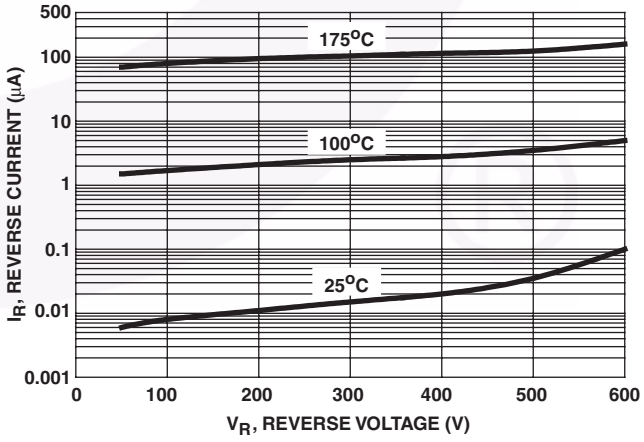


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

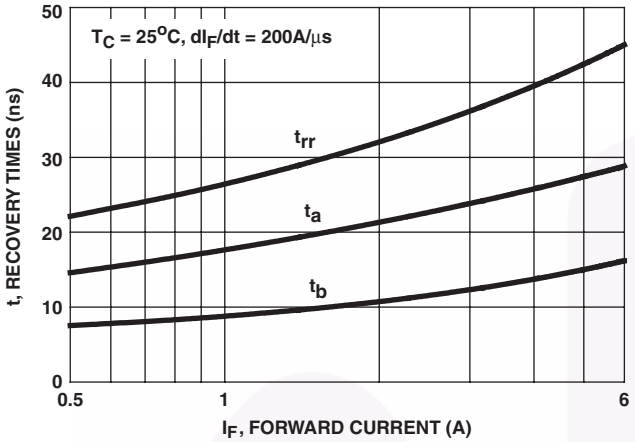


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

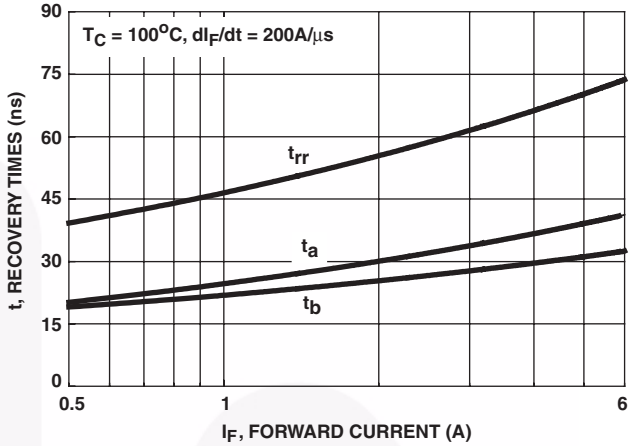


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

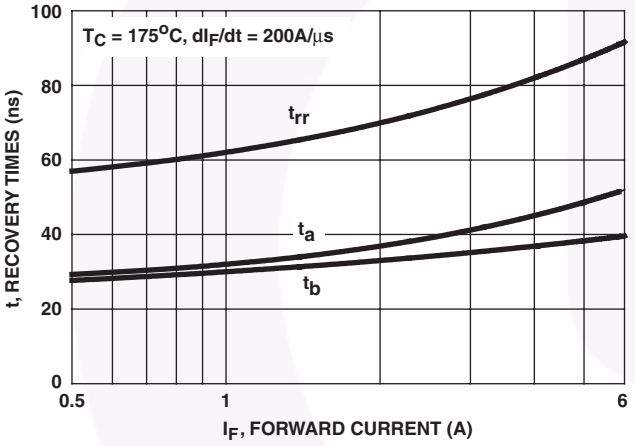


FIGURE 5. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

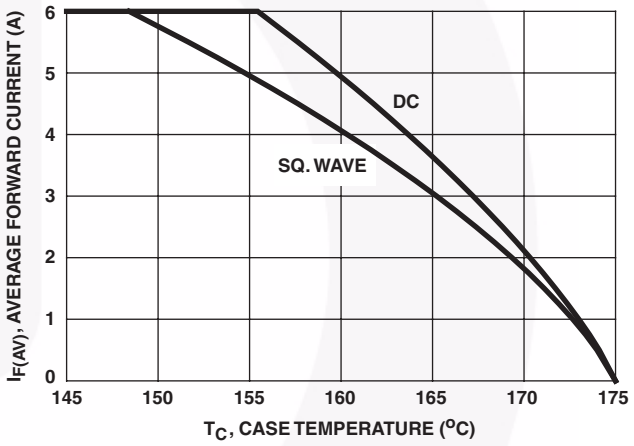


FIGURE 6. CURRENT DERATING CURVE

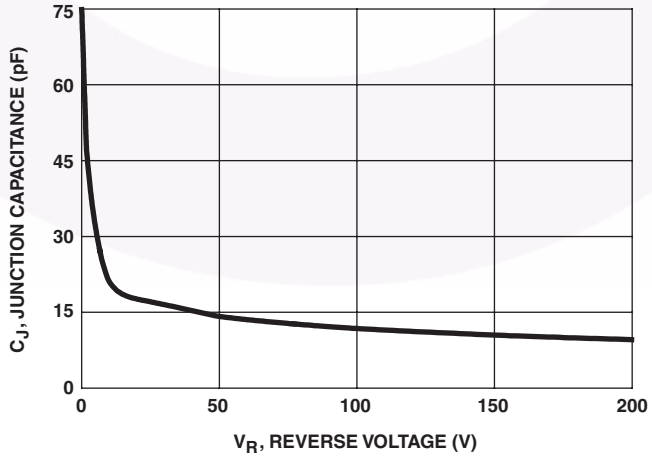


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

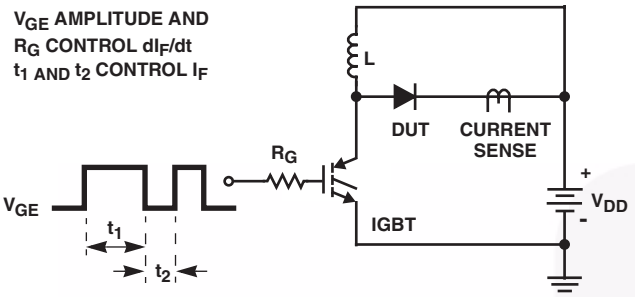


FIGURE 8. t_{rr} TEST CIRCUIT

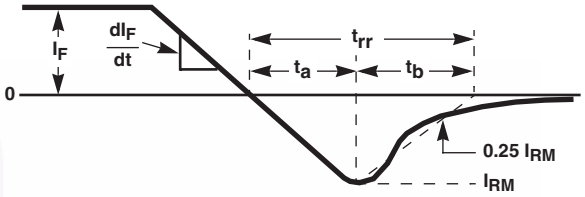


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

I = 1A
L = 20mH
R < 0.1Ω
$E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$
Q_1 = IGBT (BV_{CES} > DUT $V_{R(AVL)}$)

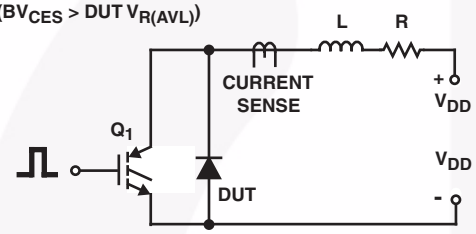


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

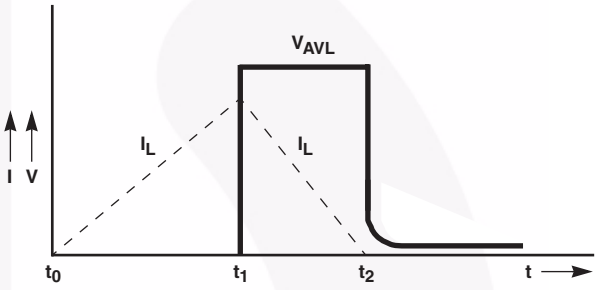


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Mechanical Dimensions

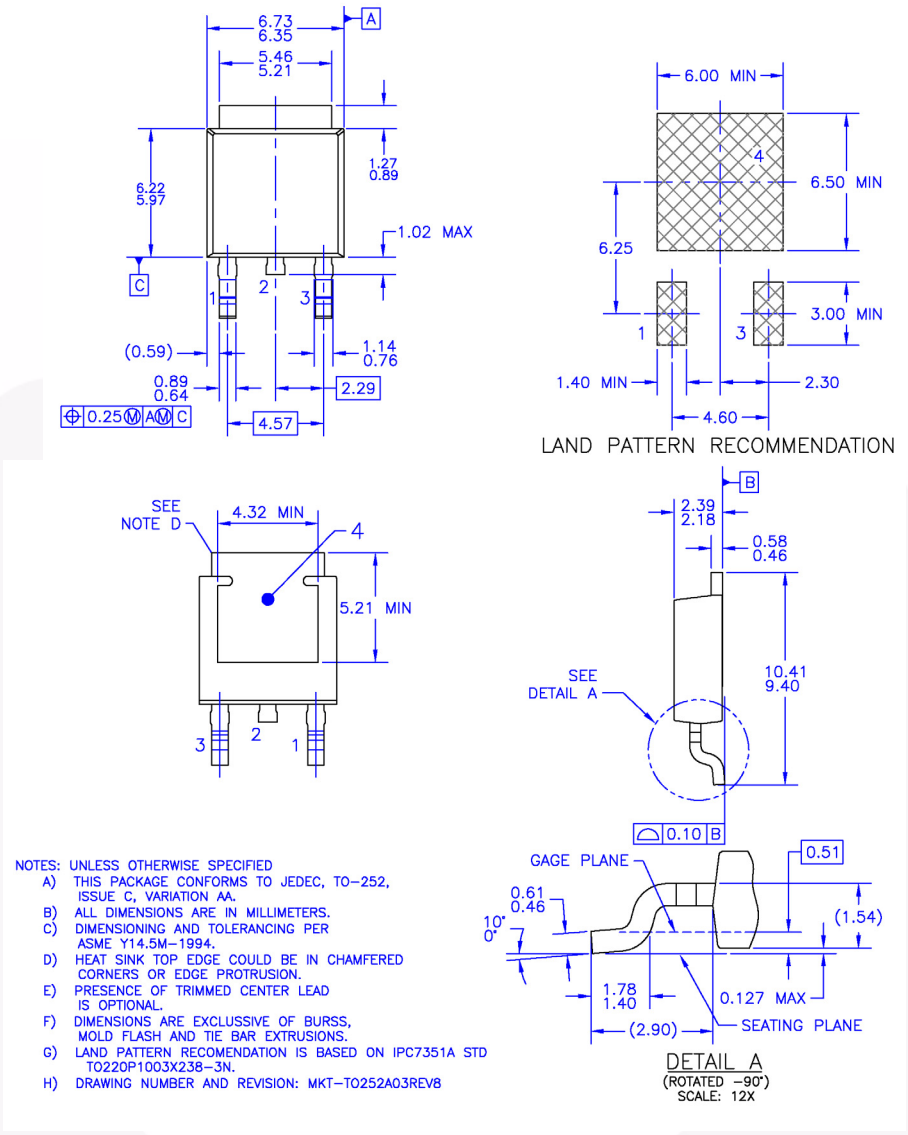


Figure 9. TO-252 3L (DPAK) - TO252 (D-PAK), MOLDED, 3 LEAD,OPTION AA&AB

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Rev. I66